

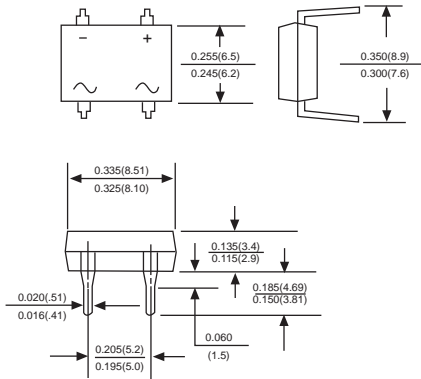


DF005 THRU DF10

SILICON BRIDGE RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

DF



FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Ideal for printed circuit boards
- ◆ Low reverse leakage
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: Molded plastic body

Terminals: Plated leads solderable per MIL-STD-750, Method 2026

Polarity: Polarity symbols marked on case

Mounting Position: Any

Weight: 0.02 ounce, 0.4 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for current capacitive load derate by 20%.

MDD Catalog Number	SYMBOLS	DF005	DF01	DF02	DF04	DF06	DF08	DF10	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward output rectified current 0.06" (1.5mm) lead length at $T_A=40^\circ C$ (Note 2)	$I_{(AV)}$	1.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50.0							Amps
Rating for Fusing ($t < 8.3ms$)	I^2t	10							A ² s
Maximum instantaneous forward voltage drop per bridge element at 1.0A	V_F	1.1							Volts
Maximum DC reverse current $T_A=25^\circ C$ at rated DC blocking voltage $T_A=100^\circ C$	I_R	10							μA
		0.5							mA
Typical Junction Capacitance (Note 1)	C_J	25							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	40							$^\circ C/W$
Operating junction temperature range	T_J	-65 to +150							$^\circ C$
storage temperature range	T_{STG}	-65 to +150							$^\circ C$

NOTES:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts.

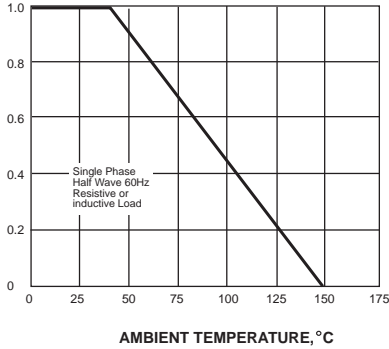
2. Unit mounted on P.C. board with 0.51" x 0.51" (13x13mm) copper pads.

MDD ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES DF005 THRU DF10

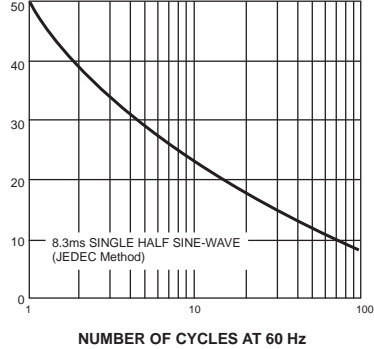
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



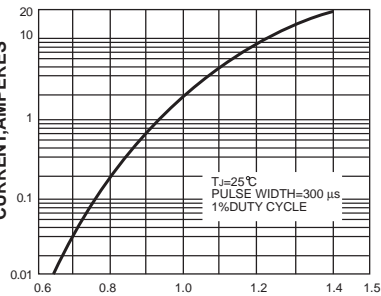
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



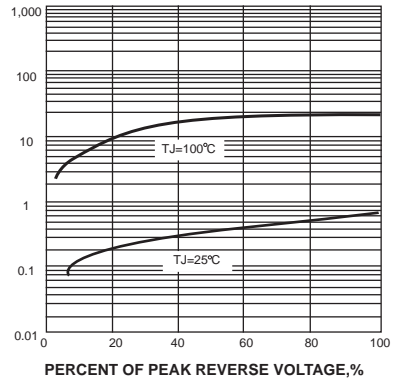
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



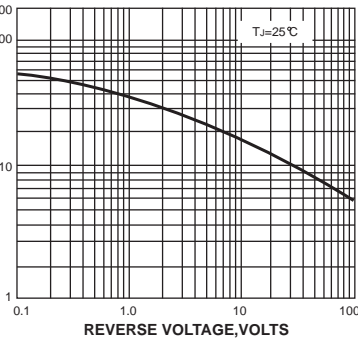
INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

